



**GENERAL INSTRUCTIONS TO THE CANDIDATES**

1. Candidates are instructed to answer the questions as per Bloom's Taxonomy knowledge level (K<sub>1</sub> to K<sub>6</sub>)
2. Candidates are strictly instructed not to write anything in the question paper other than their roll number.
3. Candidates should search their pockets, desks and benches and handover to the Hall Superintendent/ Invigilator if any paper, book or note which they may find therein as soon as they enter the examination hall.
4. Candidates are not permitted to bring electronic watches with memory, laptop computers, personal systems, walkie-talkie sets, paging devices, mobile phones, cameras, recording systems or any other gadget / device /object that would be of unfair assistance to him / her.
5. Corrective measures as per KCT examination policies will be imposed for malpractice in the hall like copying from any papers, books or notes and attempting to elicit the answer from neighbours.

**B.TECH DEGREE EXAMINATIONS: JUNE 2015**

(Regulation 2014)

Second Semester

**BIOTECHNOLOGY**

U14PHT206 : APPLIED PHYSICS

**Time: Three Hours**

**Maximum Marks: 100**

**Answer all the Questions:-**

**PART A (10 x 1 = 10 Marks)**

1. Matching type item with multiple choice code

[K<sub>1</sub>]

<b>List I</b>	<b>List II</b>
A. Mobility	i. $\Omega^{-1}\text{m}^{-1}$
B. Thermal Conductivity	ii. $\text{m}^2\text{V}^{-1}\text{s}^{-1}$
C. Electrical Conductivity	iii. $\text{W}\Omega\text{K}^{-2}$
D. Lorentz Number	iv. $\text{Wm}^{-1}\text{K}^{-1}$





**Answer any FIVE Questions:-**

**PART C (5 x 14 = 70 Marks)**

**(Answer not more than 300 words)**

**Q.No. 21 is Compulsory**

21. (i). Describe any two methods with neat sketch the synthesis of Carbon Nano Tubes. (10) [K<sub>1</sub>]  
(ii). Point out the important properties of Carbon Nano Tubes. (4) [K<sub>1</sub>]
22. (i). Derive an expression for the density of energy states and based on that calculate the carrier concentration in metals. (10) [K<sub>2</sub>]  
(ii). Superconducting tin has a critical temperature of 3.7K at zero magnetic field and it has a critical field of 0.0306 Tesla. Find the critical field at 2K. (4) [K<sub>2</sub>]
23. (i). Define Hall effect and derive an expression for Hall voltage and Hall Co-efficient in a semiconducting material. (10) [K<sub>2</sub>]  
(ii). For a silicon semiconductor with a band gap of 1.12eV, determine the position of the Fermi level at 300K if  $m_e^* = 0.12 m_o$  and  $m_h^* = 0.28 m_o$ . (4) [K<sub>2</sub>]
24. (i). Give the Weiss theory of ferromagnetism and derive an expression for its susceptibility. (10) [K<sub>2</sub>]  
(ii). Calculate the electronic polarisability of Se atom. The atomic radius of Se is 0.12nm. (4) [K<sub>2</sub>]
25. (i). What is shape memory effect? Discuss their characteristics, properties and applications. (7) [K<sub>1</sub>]  
(ii). Discuss in detail the properties and applications of Metallic glasses. (7) [K<sub>1</sub>]
26. (i). Discuss the construction and working of Scintillation detector. (7) [K<sub>1</sub>]  
(ii). Explain the method of obtaining nuclear image of an organ of our body using Positron Camera. (7) [K<sub>1</sub>]

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